Measurements of Magnetic Field Penetration of Materials for Superconducting Radiofrequency (SRF) Cavities

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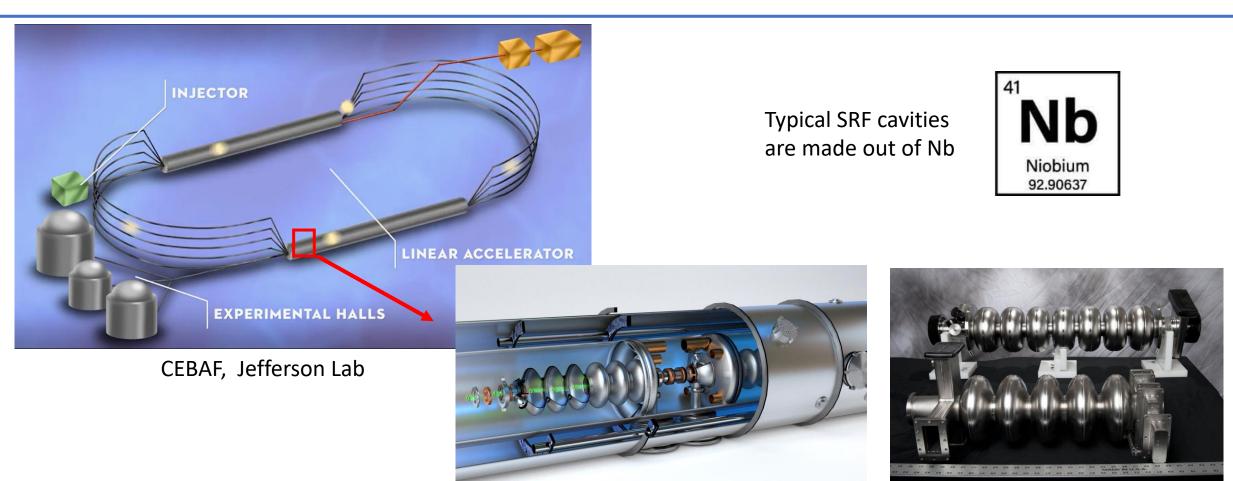
Introduction







Introduction | MFP Magnetometer Design and Fabrication | Calibration | Measurements 1/2/3 | Conclusions 1/2/3



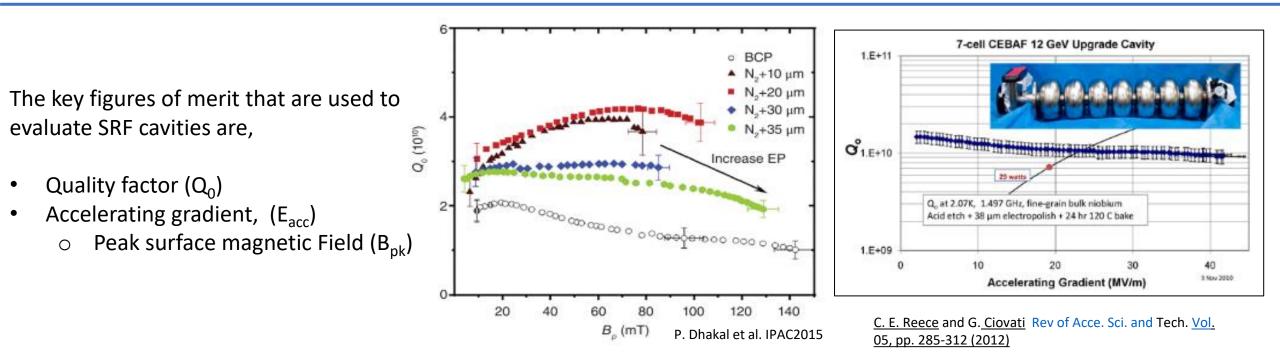
Superconducting RF accelerating cavity is a key component of the particle accelerators which impart energy to charged particles

five- and seven-cell niobium cavities produced at Jefferson Lab's SRF Institute









The ratio of the stored energy to power disipation ,
$$Q_o = \frac{\omega_o U}{P_c} \propto 1/R_s$$

The ratio of the accelerating voltage per cell V to the cell length, $E_{acc}(MV/m) = \frac{V}{L} \propto B_{pk}$ (mT)

Peak Surface Magnetic Field

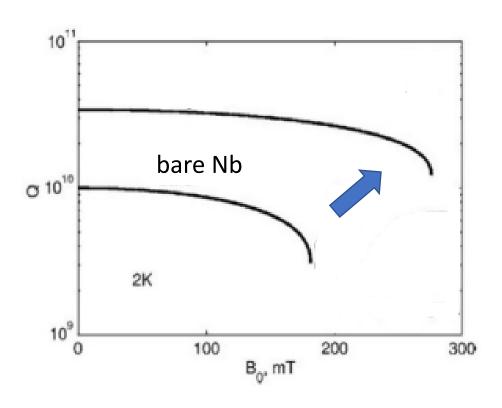


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Why new materials ?



Nb SRF cavities can achieve

- High quality factor $\sim 10^{10}$ - 10^{11}
- High Accelerating gradient \sim 52 MVm⁻¹ (at 1.3–2 K and 1–2 GHz)
- Peak surface magnetic field has reached close to its theoretical limit

 $H_{max} \approx H_c = 200 \text{ mT}$

For further improved RF performance of the cavity, materials other than Nb are needed to characterize.







What Choices for New Material ?

Choices are based on,



- Higher *H_c*
- Higher H_{c1}

For high accelerating gradients

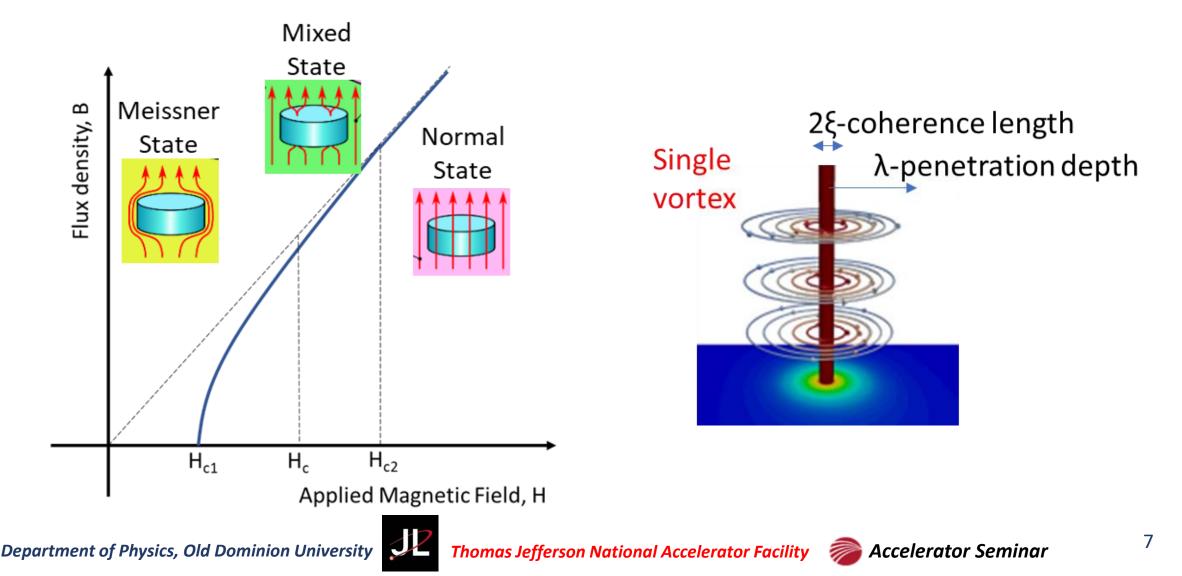
$$E_{acc} \alpha B_{pk}$$



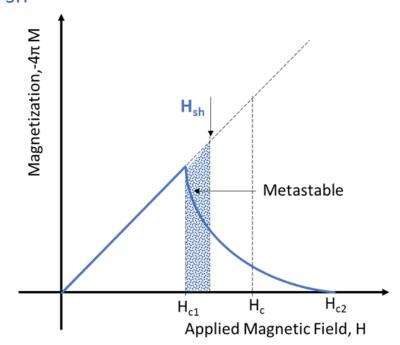


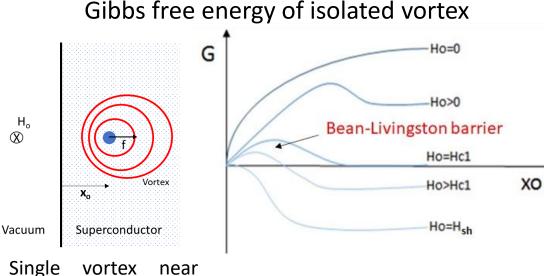


Field Penetration into Type II Superconductor

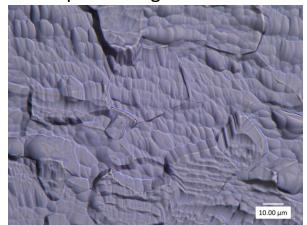


In Type – II superconductors, the Meissner state can persist metastably above H_{c1} but only up to H_{sh}





Optical Image of BCP Nb



- Vortices have to overcome surface barrier even at H> H_{c1}
- Surface barrier vanishes at superheating field H_{sh}
- Surface barrier weaken at defects and vanishes at H= H_p where H_{c1}<H_p<H_{sh} even at H_p<H_{c1}
- Early flux penetration limits the SRF cavity performances at higher fields



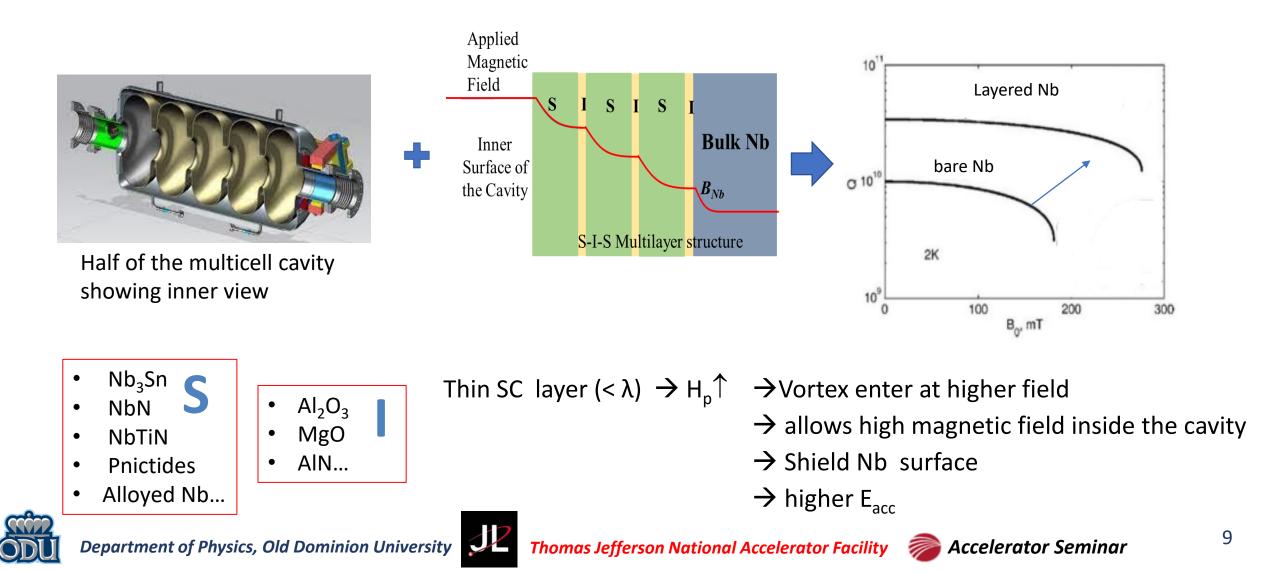


ideal surface parallel

to external field

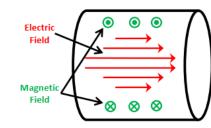


SIS Multilayers on Nb : Shield Nb at high surface magnetic field



Objective of the project

- Surface field at onset of flux penetration, B_p is a useful characteristic to • explore the shielding effect of SIS multilayers.
- Techniques to measure the onset of magnetic field penetration into superconducting samples need to be developed emulating the field profile at wall of the SRF cavity operating at fundamental accelerating mode.
- In this project, Magnetic Field Penetration (MFP) Magnetometer was • designed, built and then implemented for measurements at Jefferson Lab.



fundamental accelerating mode TM_{010} used for acceleration





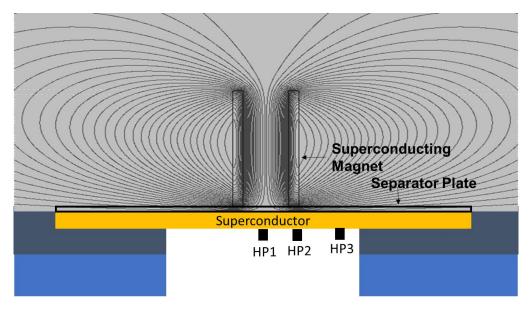
Magnetic Field Penetration (MFP) Magnetometer



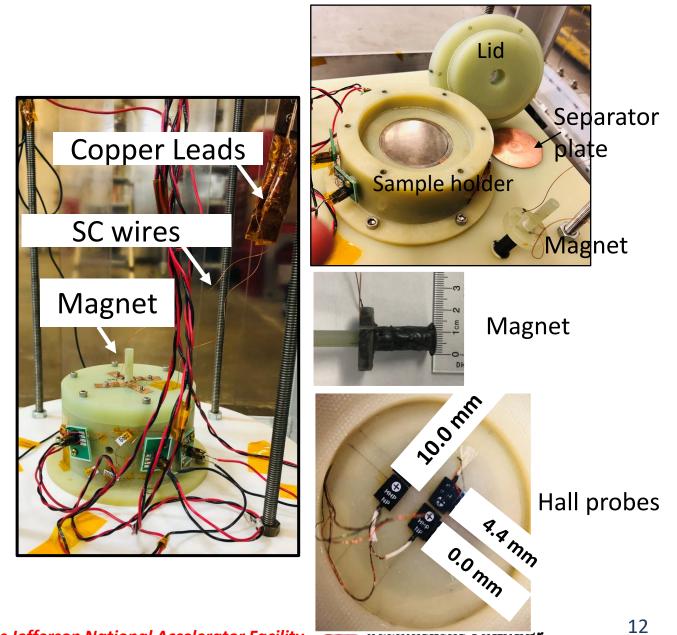




investigate the shielding effect of To multilayers, Magnetic Field Penetration (MFP) magnetometer is designed, built and implementing for magnetic field penetration measurements.

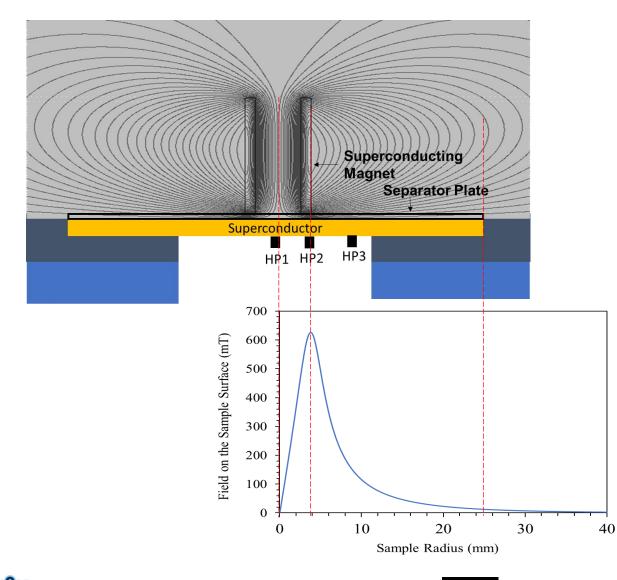


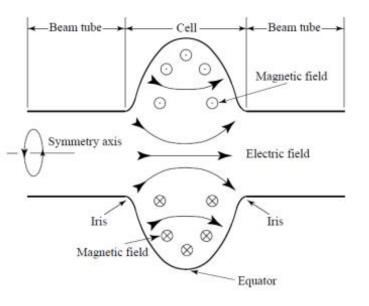
Basic Experimental Setup



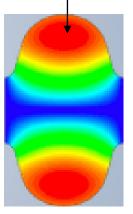








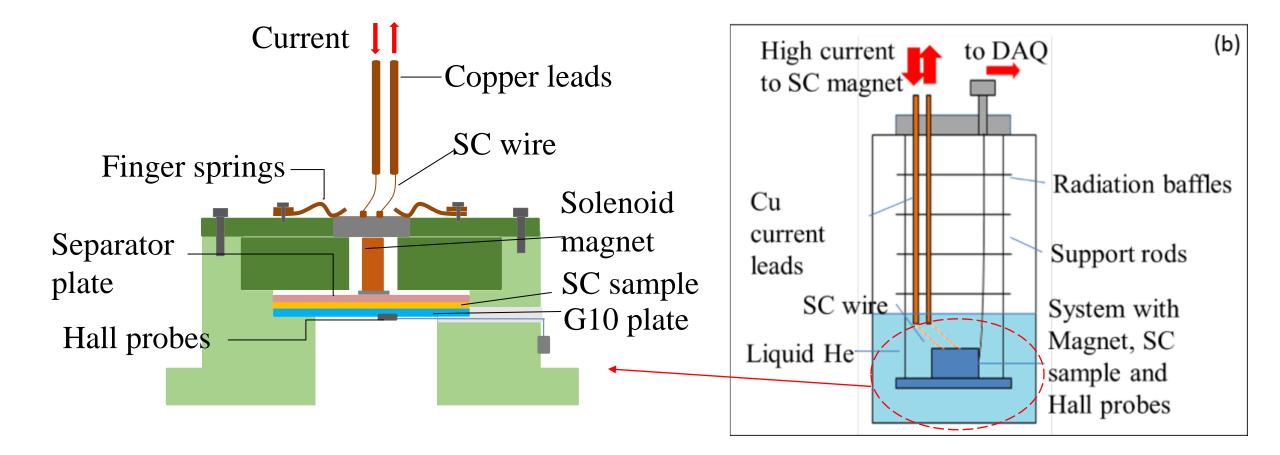
Peak Magnetic field



- In the Meissner state, sample act as a magnetic mirror.
- A current is generated at the surface of the superconductor in order to cancel the applied field at the surface.
- The combined applied and induced fields result is parallel to the sample surface, which resembles the magnetic field profile at the equator of the accelerating cavity.





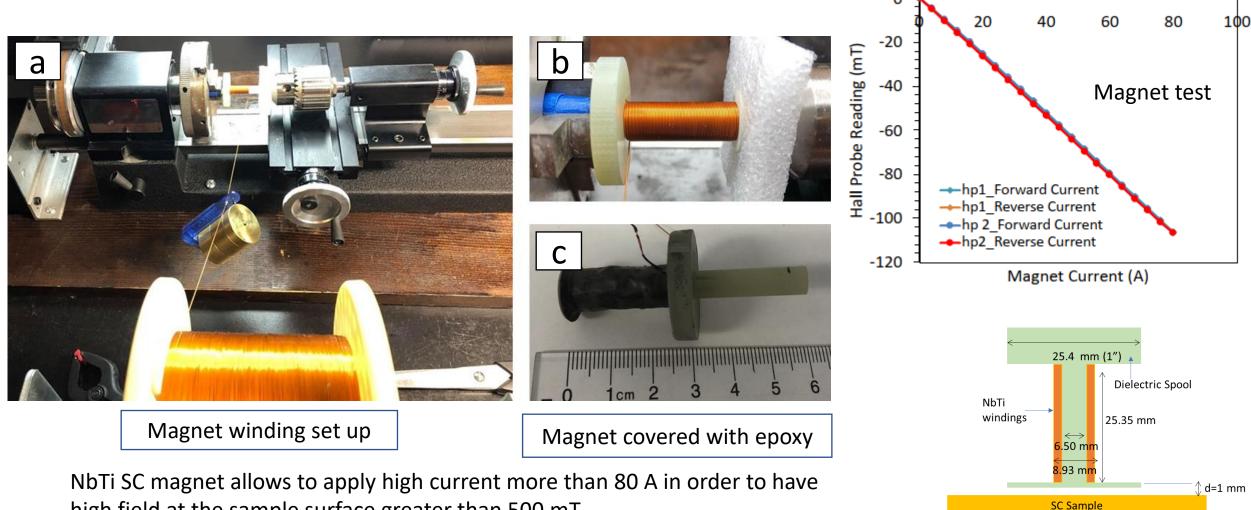








Magnet Fabrication



high field at the sample surface greater than 500 mT

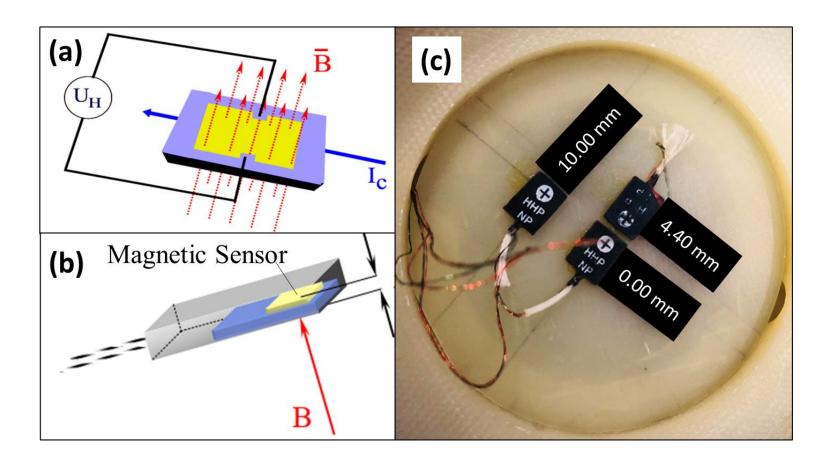






50.8 mm (2")

Hall Probes used in the setup



 (a) HHP-NP Hall probes used in the experimental setup that can detect the component of the magnetic field perpendicular to the probe

(b) the Hall sensor located inside the probe covered with the resin

(c) configuration of the Hall probes mounted at the bottom of the sample

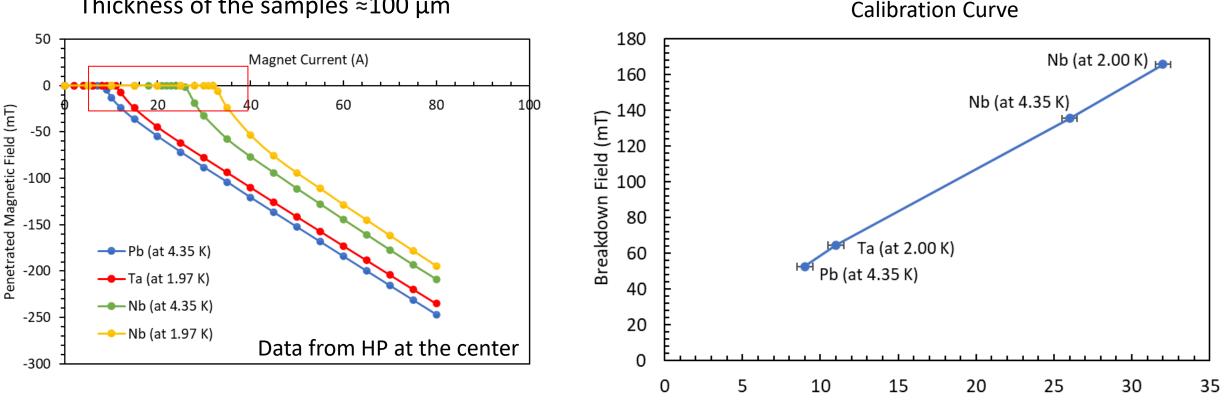






Setup Calibration: Method 1

Thickness of the samples $\approx 100 \ \mu m$



Breakdown Current (A)

- Ref:
- G. Chanin and J. P. Torre, "Critical-field curve of superconducting lead," Phys. Rev. B 5, 4357–4364 (1972).
- D. K. Finnemore, T. F. Stromberg, and C. A. Swenson, "Superconducting properties of high-purity niobium," Phys. Rev. 149, 231-243 (1966)
- C. H. Hinrichs, C. A. Swenson, "Superconducting critical field of tantalum as a function of temperature and pressure", Phy. Rev. Vol. 123, No. 4, 1961



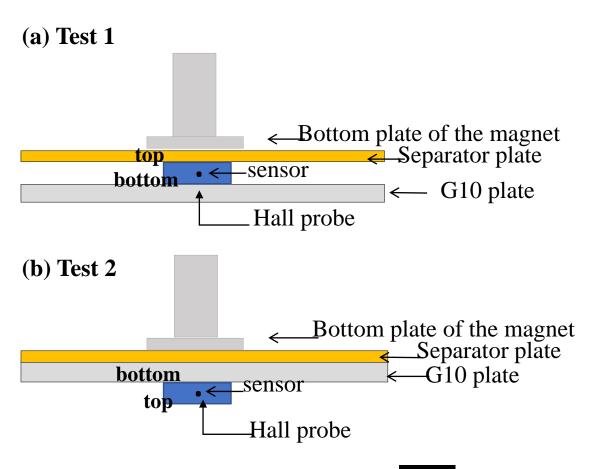
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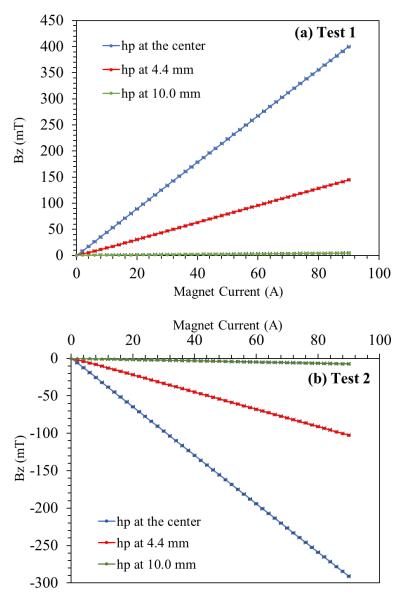




Setup Calibration: Method 2

Measurements of B, with increasing magnet current

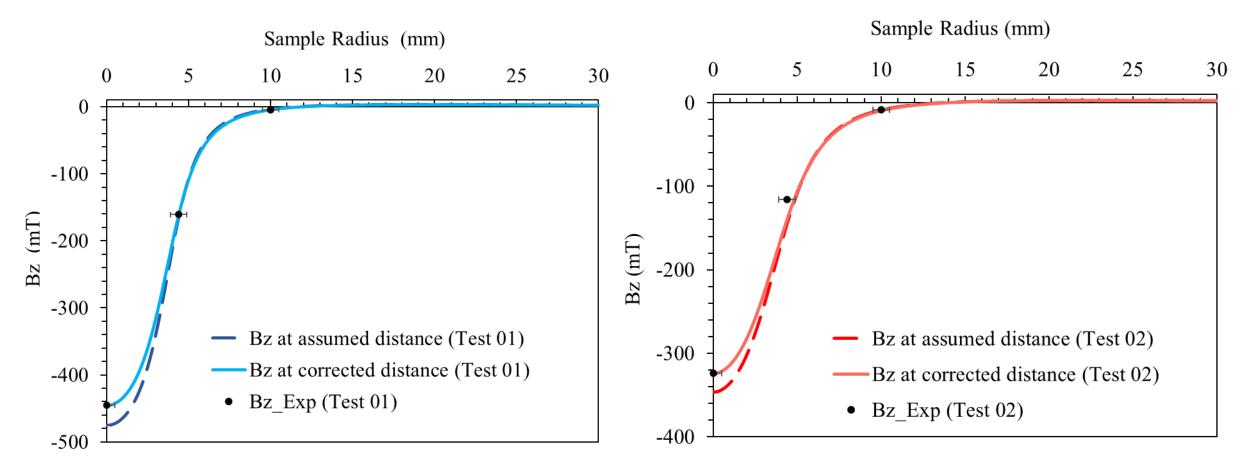






Test 01

Test 02



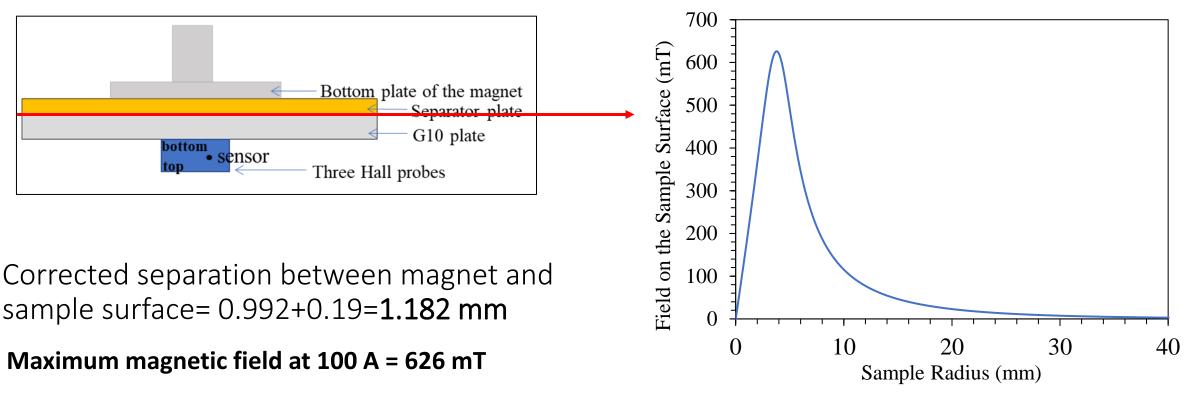
Corrected-Assumed = 0.19 mm < less than magnet wire







Calibrated Magnetic field on the surface in Meisnner state at 100 A of current









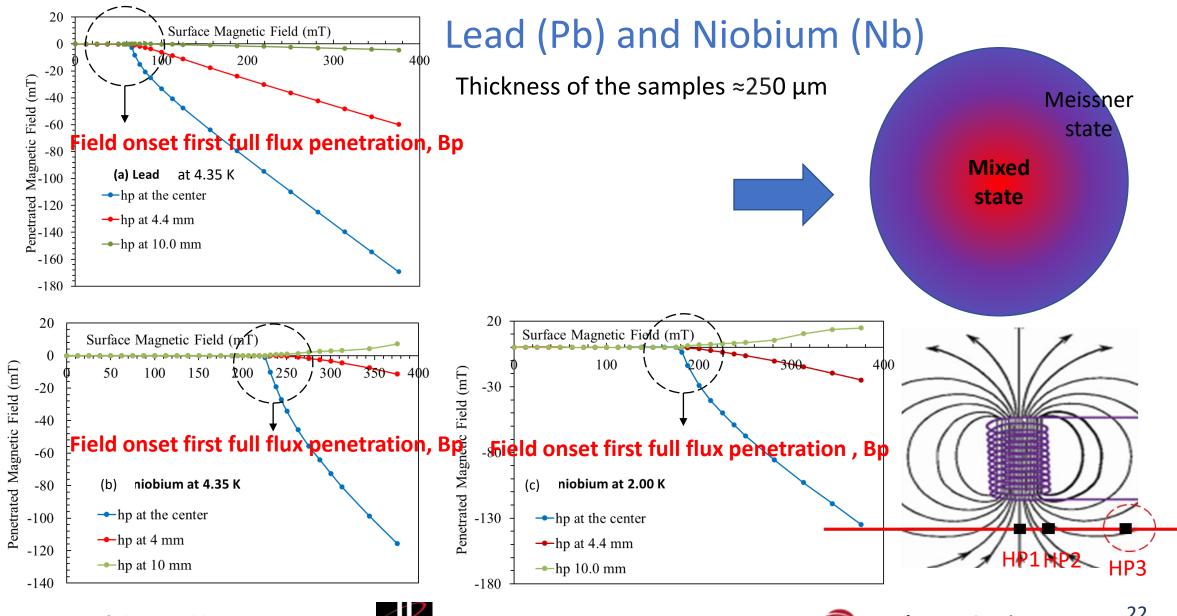
1-Measurements on Bulk Superconductors



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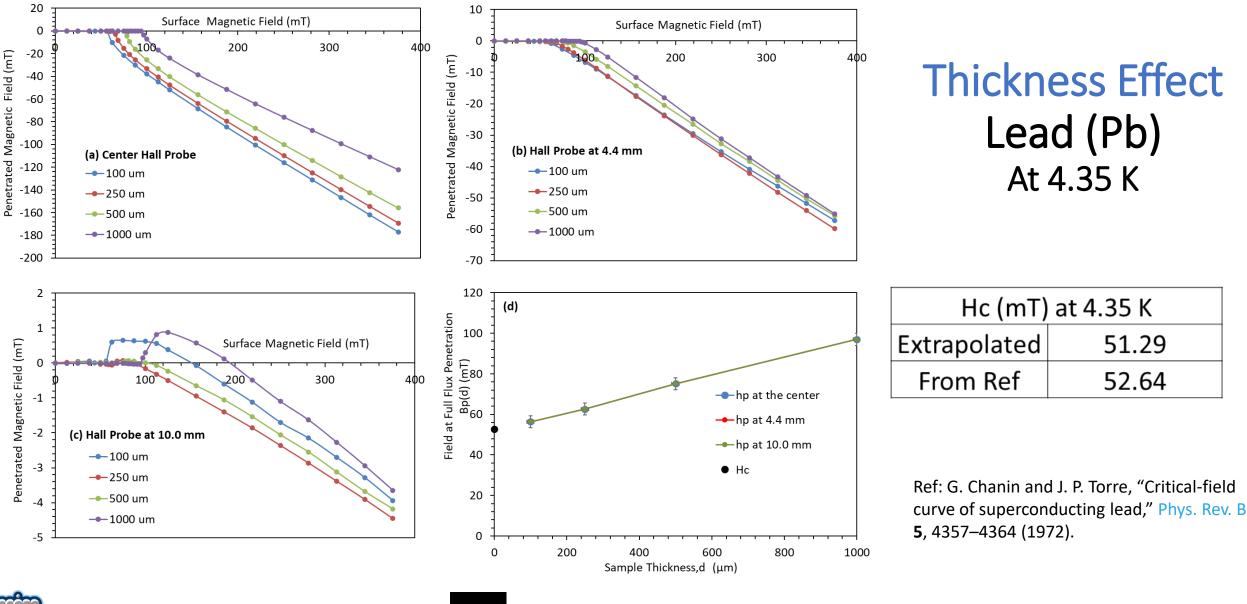






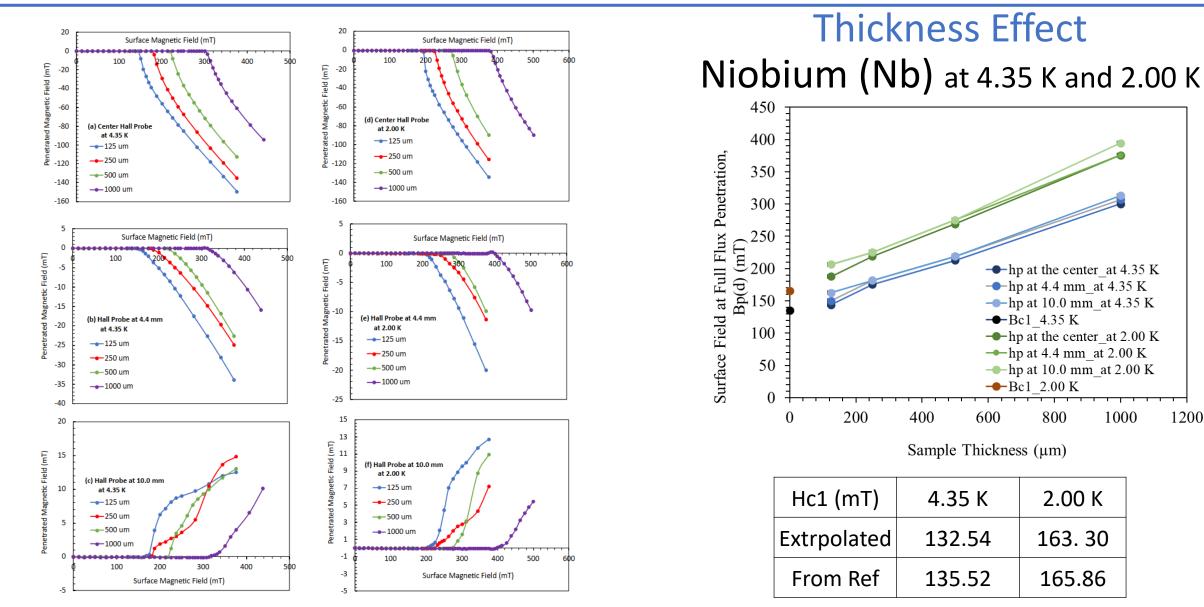












Ref: D. K. Finnemore, T. F. Stromberg, and C. A. Swenson, "Superconducting properties of high-purity niobium," Phys. Rev. 149, 231–243 (1966) **Thomas Jeffers**

Conclusions

- MFP Magnetometer has been developed to detect the field onset of magnetic flux penetration, B_p through flat samples of SRF materials.
- Testing the setup on Pb and Nb bulk samples was successful. The variation of B_p is linear with the thickness of sample and it has reproduced the well-known values of critical magnetic fields of these materials.





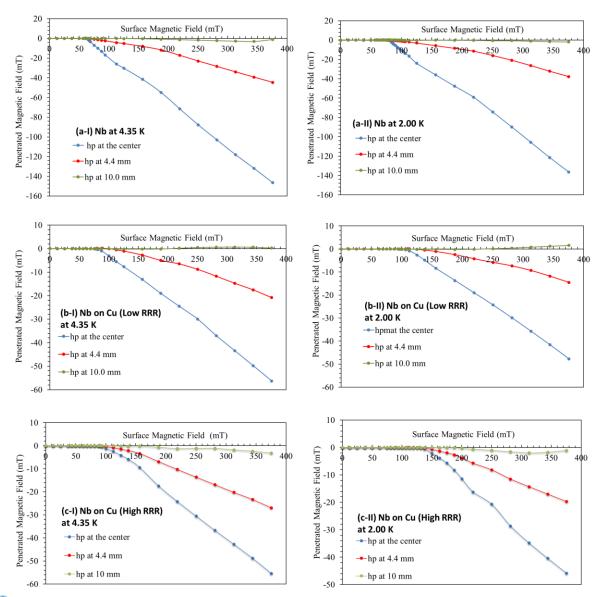


2-Measurements on Thin Film Superconductors

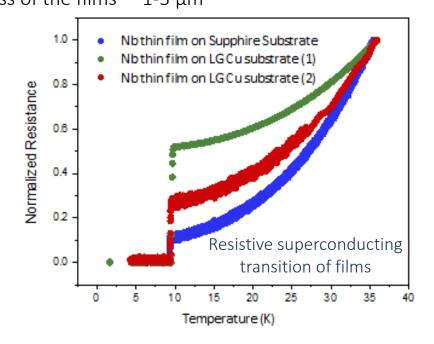








Magnetic Feld Penetration Measurements on Nb thin film by Electron Cyclotron Resonance (ECR) at Jefferson Lab. Thickness of the films ~1-3 μ m



Sample	RRR	Тс	ΔТс	Bp (mT)	
				4.35 K	2.00 K
Nb on Sapphire	332	9.31	0.03	62.6	80.1
Nb on LGCu (1)	34	9.57	0.28	78.3	97.0
Nb on LGCu (2)	190	9.47	0.24	90.8	125.2

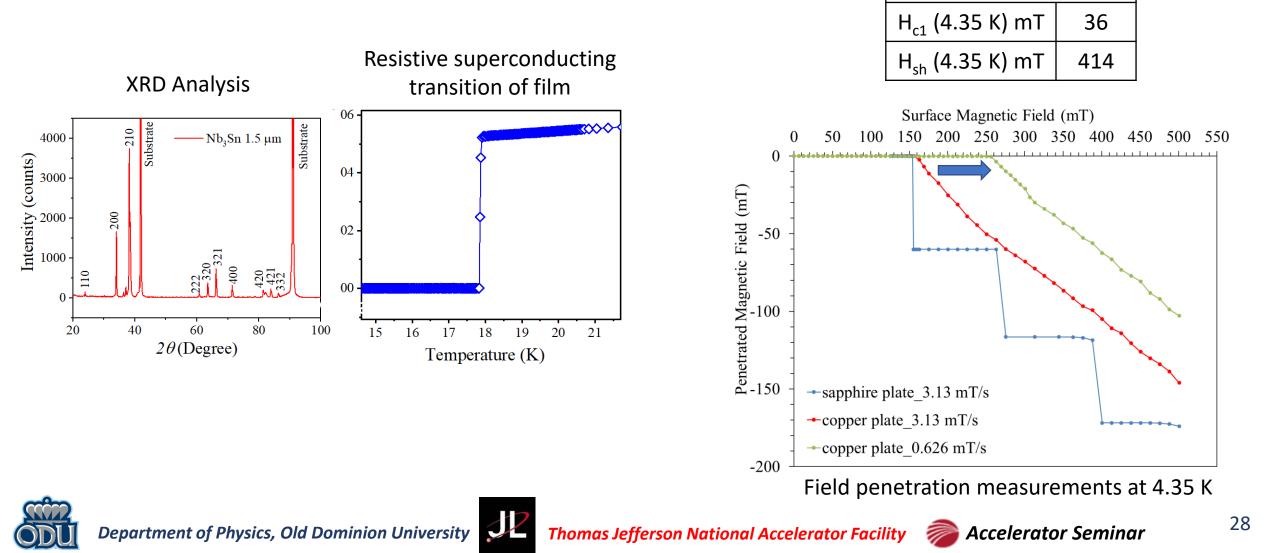


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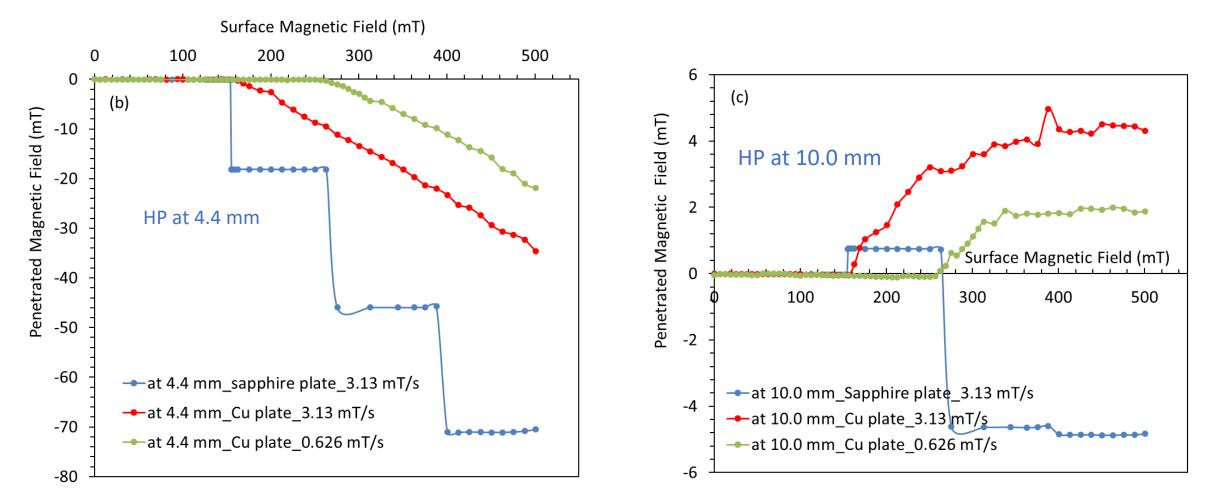


1.5 μm thick **Nb**₃**Sn thin film** grown on sapphire wafer by multilayer sequential sputtering at room temperature and annealed at 950 °C at Jefferson Lab.

Nb₃Sn Critical Fields



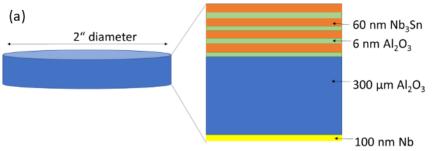
Field penetration measurements from Hall Probe at 4.4 mm and 10.0 mm at 4.35 K on 1.5 μ m thick Nb₃Sn thin film grown on Al₂O₃ wafer by multilayer sequential sputtering at room temperature and annealed at 950 °C at Jefferson Lab.



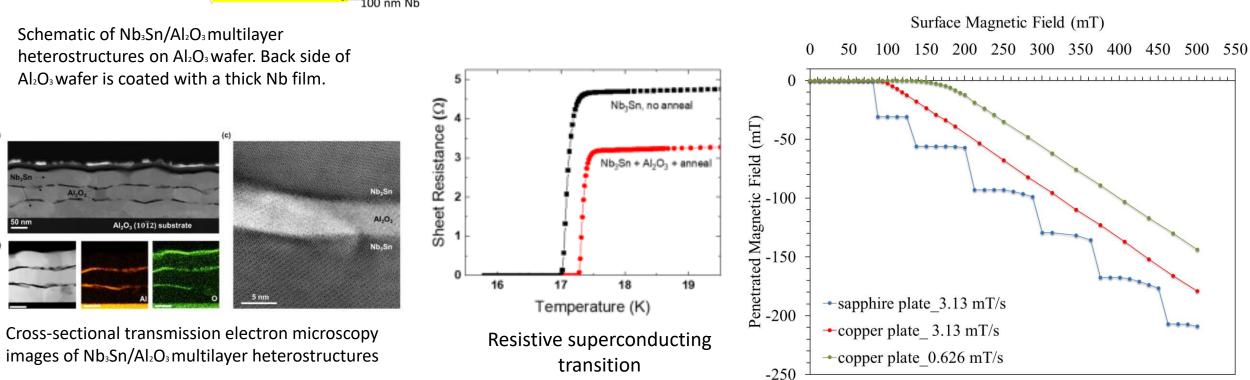








Nb₃Sn/Al₂O₃ multilayer grown on sapphire wafer by high-temperature confocal sputtering at the University of Wisconsin-Madison. This multilayer sample consists of four 60 nm Nb₃Sn layers separated by 6 nm Al₂O₃ interlayers.



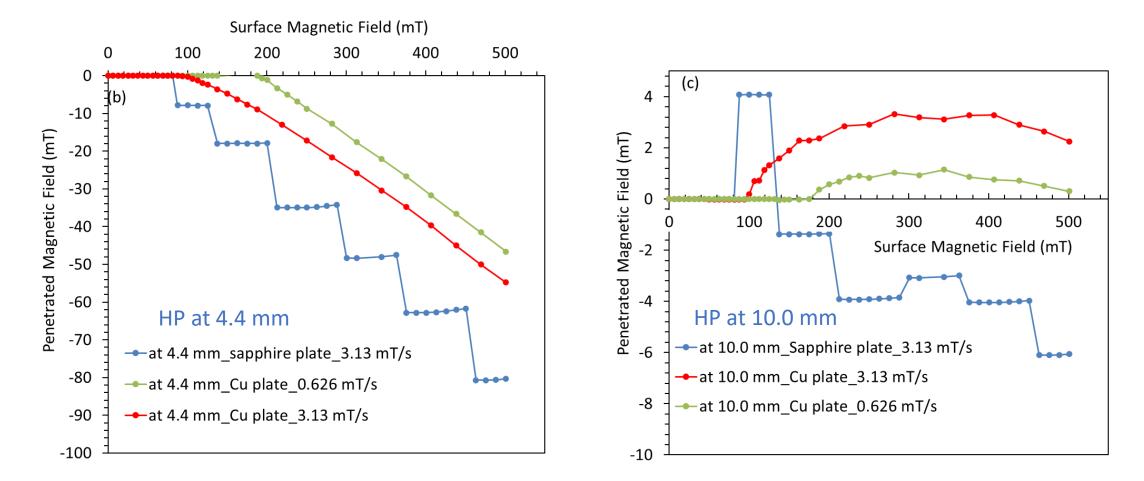
Sundahl et al , Sci. Rep. 11, 7770 (2021)

Magnetic Feld Penetration Measurements





Magnetic Feld Penetration Measurements Hall Probe at 4.4 mm and 10.0 mm at 4.35 K on Nb₃Sn/Al₂O₃ multilayer grown on Al₂O₃ wafer by high-temperature confocal sputtering at the University of Wisconsin-Madison. This multilayer sample consists of four 60 nm Nb₃Sn layers separated by 6 nm Al₂O₃ interlayers.









Conclusions

- Thin film measurements of Bp using MFP magnetometer was successful and this is a nondestructive technique for thin film measurements.
- The dependent of Bp with material purity was observed using Nb thin films coated on Cu substrates.
- Low conductive thin film materials, such as Nb₃Sn films, and multilayers exhibit flux jumps due to thermomagnetic flux avalanches. These flux jumps were mitigated by improving heat transfer across the sample and slowing down the magnet ramp rate.







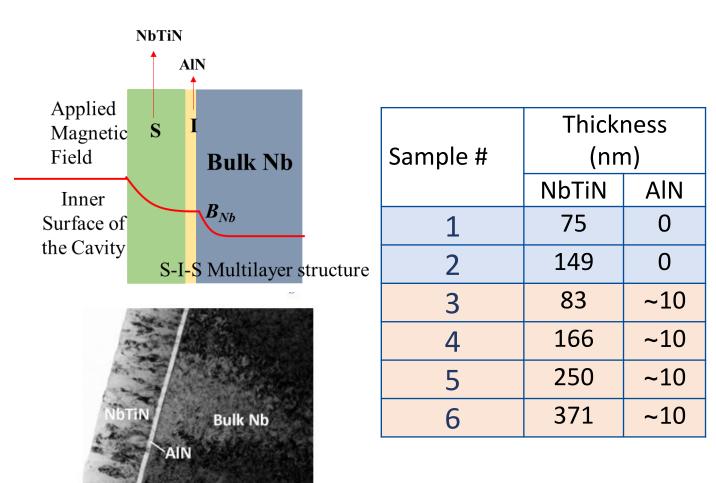
3-Measurements on Multilayered Niobium







- NbTiN and AlN thin layers are deposited on bulk Nb using reactive Direct Current Magnetron Sputtering (reDCMS) in an Ultra-High Vacuum (UHV) system with a base pressure of 10⁻¹⁰Torr.
- The Nb substrates are prepared by buffered chemical polishing (BCP) removing 5um from the surface.
- The films were deposited at 450 °C on bulk Nb after a 24 hour bake at 600 °C, then post-annealed at 450 °C for 4 hours.



Cross-sectional transmission electron microscopy image of NbTiN/AIN/Nb structure A.-M. Valente-Feliciano et al, SRF2013

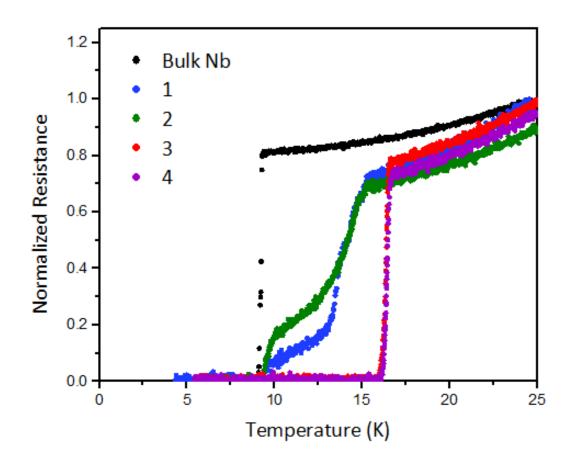






Resistance measurements done by standard four-point probe method

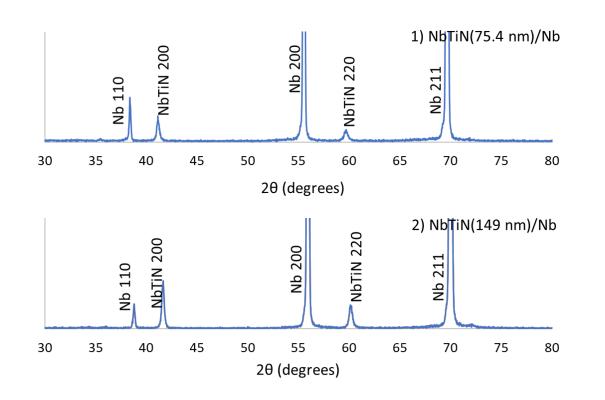
Sample #	Thickness (nm)		Tc (K)	ΔT (K)
	NbTiN	AIN		
1	75	0	16.2	0.40
2	149	0	16.3	0.30
3	83	~10	14.4	1.49
4	166	~10	15.7	0.79







Single layer NbTiN on Nb substrate



The crystallographic structures of deposited thin films were examined by X-ray diffraction (XRD) analysis

SEM images and relevant Inverse Pole Figure (IPF) map from EBSD showing the polycrystalline nature of the deposited film on bulk Nb

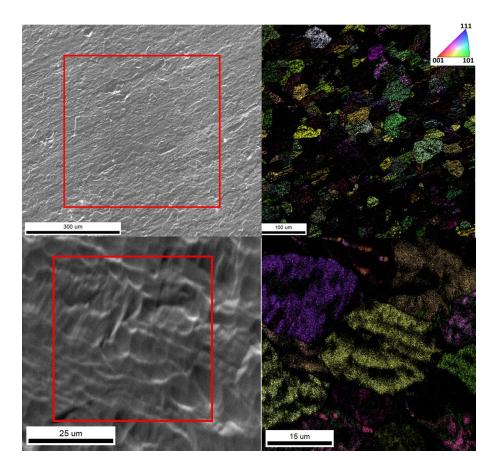




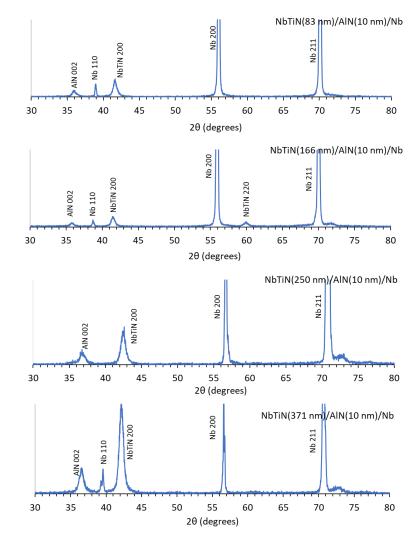
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NbTiN/AlN on Nb Substrate



SEM images and relevant Inverse Pole Figure (IPF) map from EBSD showing the polycrystalline nature of the deposited film on bulk Nb

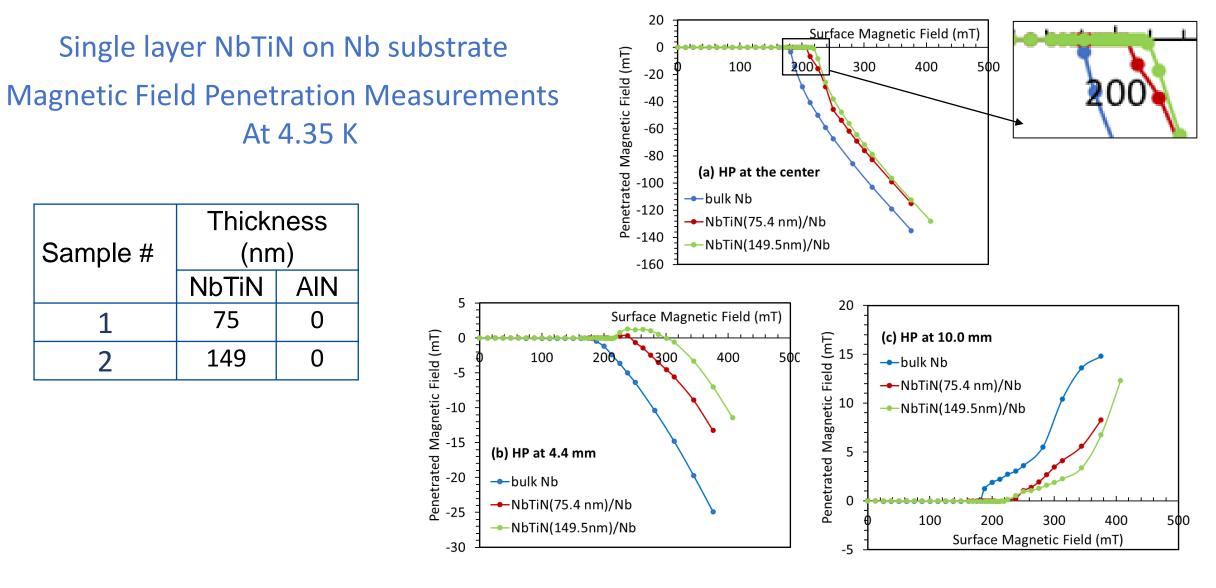


The crystallographic structures of deposited thin films were examined by X-ray diffraction (XRD) analysis





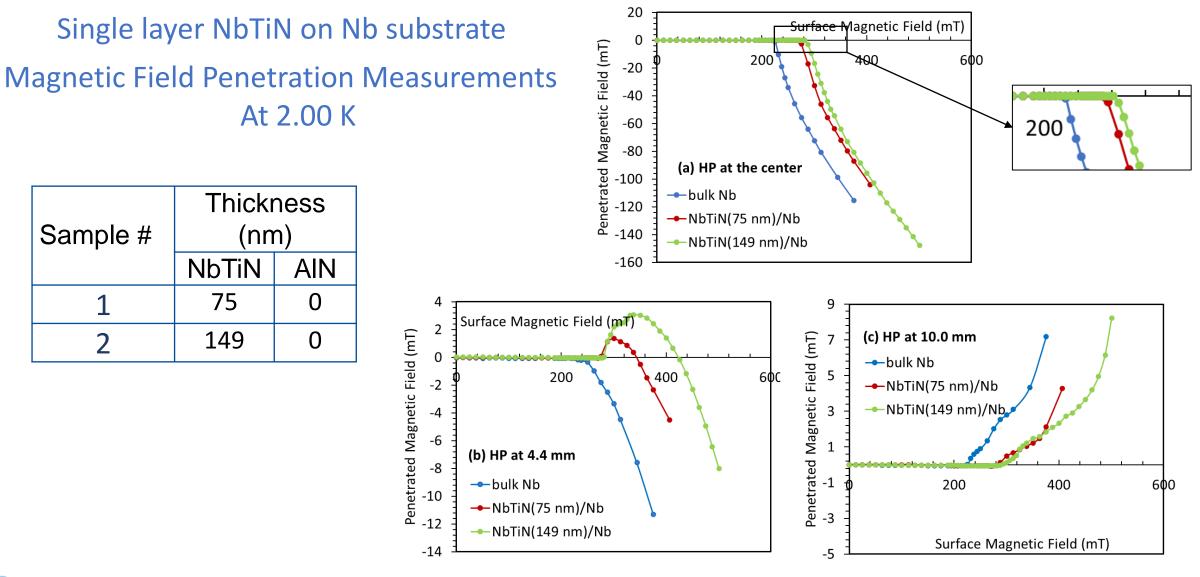












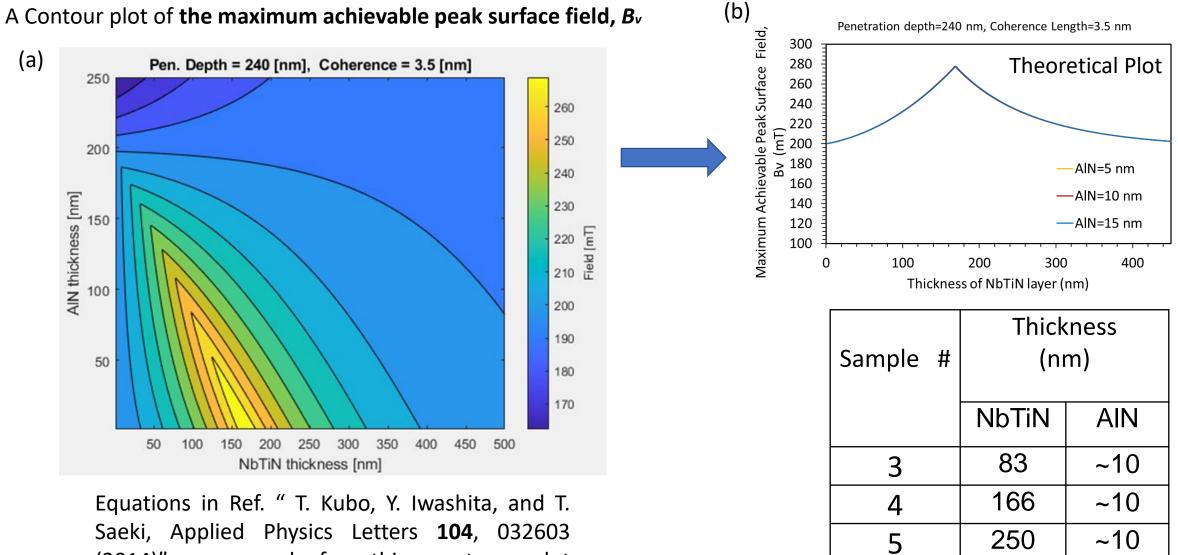




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Saeki, Applied Physics Letters **104**, 032603 (2014)" used for this contour plot are



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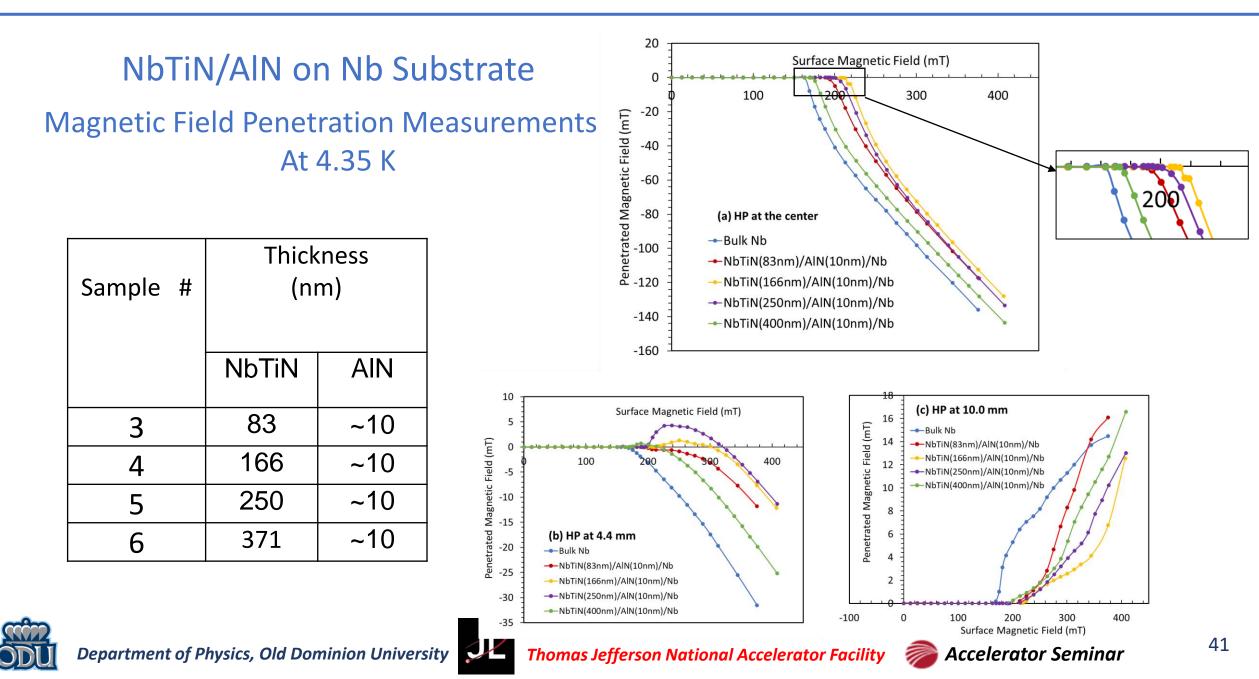


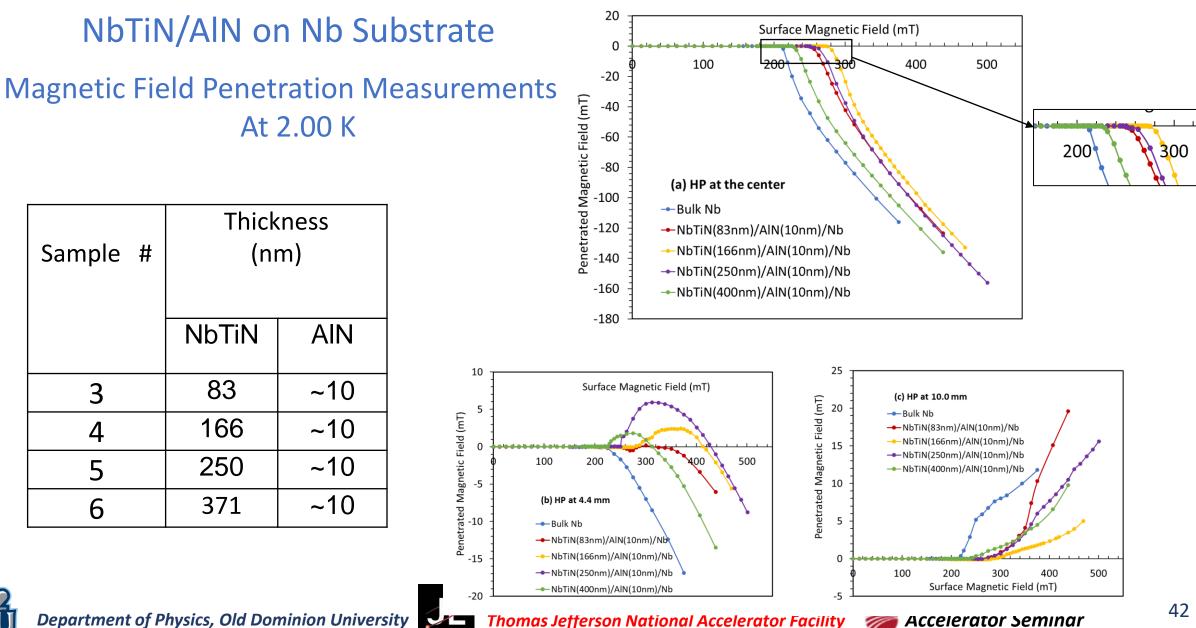
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371

40

~10

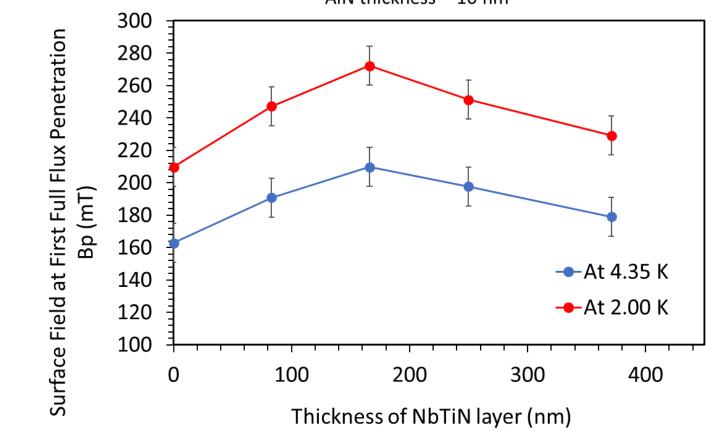




The surface field at first full flux penetration, B_p at 4.35 K and 2.00 K for different NbTiN layer thickness maintaining constant AlN layer thickness ~ 10 nm

Sample #	Thickness (nm)	
	NbTiN	AIN
3	83	~10
4	166	~10
5	250	~10
6	371	~10

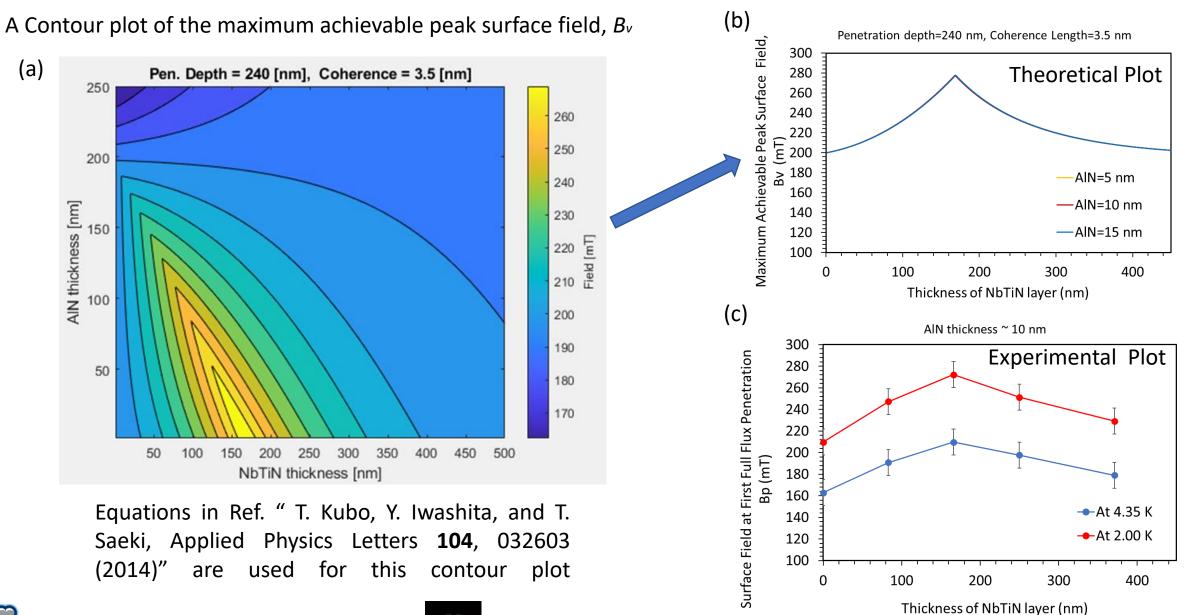
~25 % increase of Bp compared to bare Nb is observed with single NbTiN and single AlN layers on bulk Nb



AlN thickness ~ 10 nm





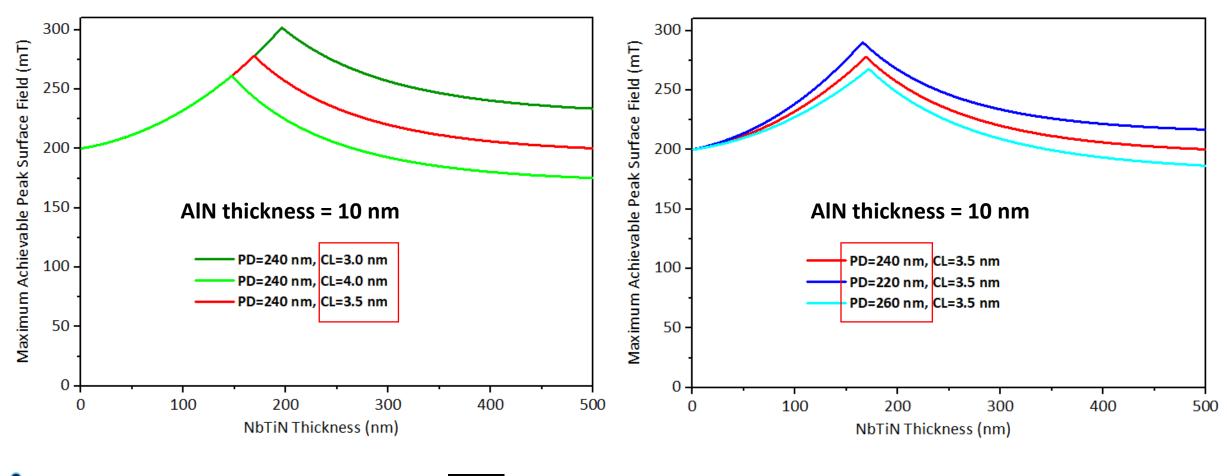




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The peak of the graph depends on the penetration depth and the coherence length of the sample.







Conclusions

- Layered Nb showed flux penetration at higher field compared to bare Nb.
- To explore multilayer concept that has been proposed to enhance peak surface magnetic field of the SRF cavity,
 - a series of NbTiN/AIN coated on BCP Nb samples with
 - o different NbTiN thickness
 - $\,\circ\,$ constant AIN thickness were tested.
- The variation of B_p confirms that the existence of optimum thickness of S layer for maximum field and that is consistent with the theory build up in "T. Kubo, Y. Iwashita, and T. Saeki, Applied Physics Letters **104**, 032603 (2014)".
- Optimum thickness of NbTiN for maximum *Bp* among measured four thicknesses is 166 nm when AlN is nearly 10 nm.

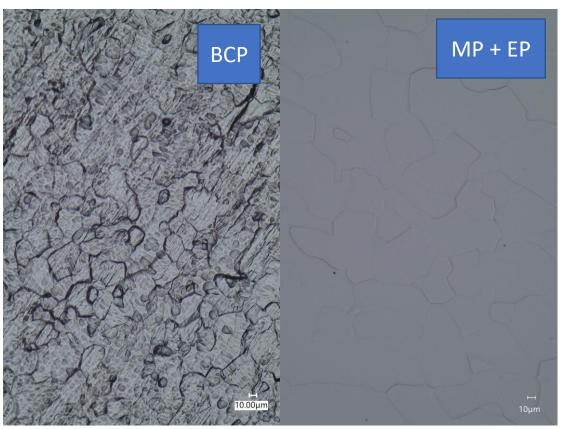






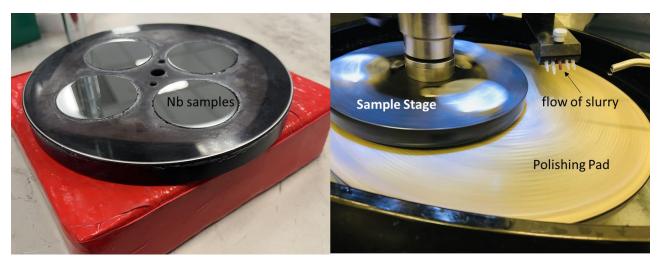
Nb substrate with different roughness: BCP vs MP+ EP

Optical Images



RMS roughness: ~ 3 μ m Substrate thickness ~ 250 um

~ 20 nm 150 um BCP- Buffered Chemical Polishing EP - Electropolishing MP- Mechanical Polishing



Mirror finished samples

Sample stage is spinning on polishing pad with flow of slurry





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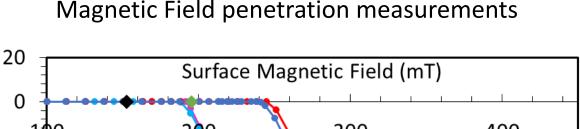


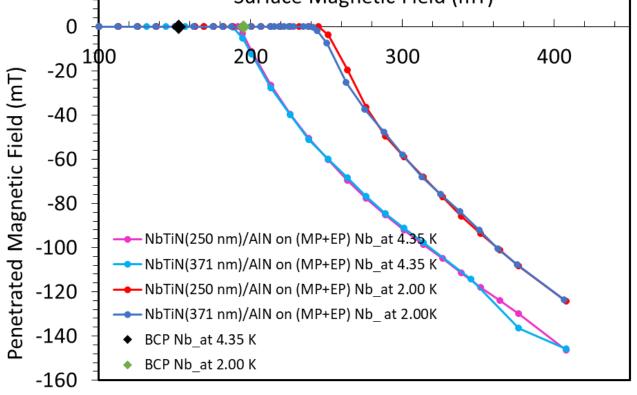
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NbTiN/AIN coated on MP+EP Nb substrate

Sample	#	Thickness (nm)	
		NbTiN	AIN
5		250	~10
6		371	~10

5-10 % increase is estimated compared to multilayer coated on BCP Nb











- Prof. Jean Delayen
- Prof. Alex Gurevich
- Prof. Anne-Marie Valente Feliciano
- Prof. Moskov Amaryan and Prof. Khan Iftekharuddin
- Dr. Gigi Ciovati
- Read Beverstock, Eric Lechner, Carrie Baxley
- Junki Makita and Salvador Sosa
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